

3/22/04

FOR PTO-1449 (Modified)
**LIST OF PATENTS AND PUBLICATIONS FOR
 APPLICANTS INFORMATION DISCLOSURE
 STATEMENT**

(Use several sheets if necessary)

ATTY. DOCKET NO.

3521.171

SERIAL NO.

10/287,864

APPLICANT
 SOMIT TALWAR, et al.

FILING DATE
 November 6, 2002

GROUP
 2881

REFERENCE DESIGNATION

U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER							DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
JD	A	4	9	0	8	4	9	3	3-13-90	Susemihl	219	121.67	
JD	B	4	3	5	6	3	7	5	10-26-82	Josephy, et al.	219	121 LH	
JD	C	6	3	6	6	3	0	8	4-2-02	Hawryluk, et al.	347	256	

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER							DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
													YES	NO

OTHER

ART (Including Author, Title, Date, Pertinent Pages, Etc.)

JD	D	Naem, Boothroyd, Calder, <i>CW Laser Annealed Small-Geometry NMOS Transistors</i> , Mat. Res. Soc. Symp. Proc. Vol. 23 (1984) pp 229-234.
JD	E	Goetzlich, Tsien, Ryssel, <i>Relaxation Behavior of Metastable AS and P Concentrations in SI After Pulsed and CW Laser Annealing</i> , Mat. Res. Soc. Symp. Proc. Vol. 23 (1984) pp 235-240

EXAMINER

Janet Q

DATE CONSIDERED

11/22/05

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.